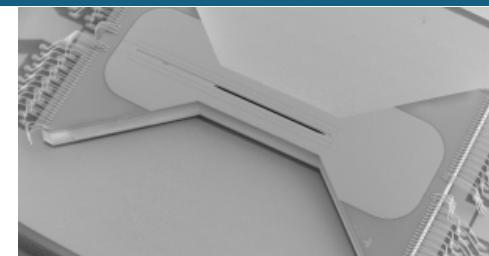
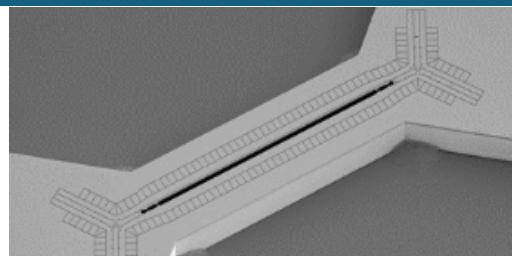
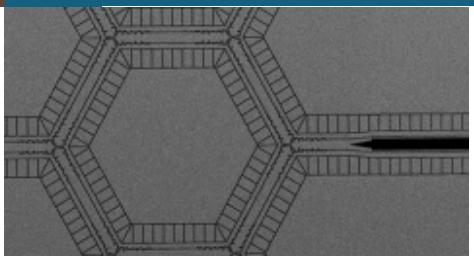




Sandia  
National  
Laboratories

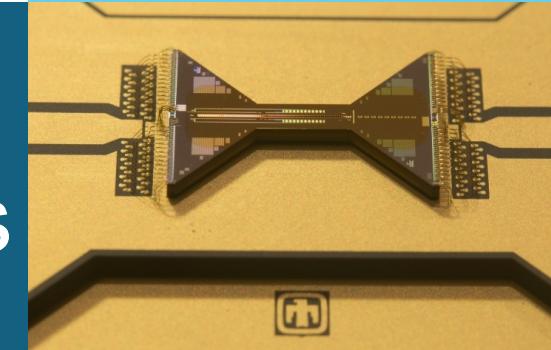
# Ion Based Quantum Computing in Microfabricated Surface Traps



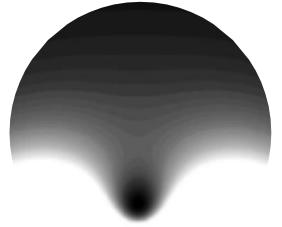
*Presented by:*

**Melissa Revelle**

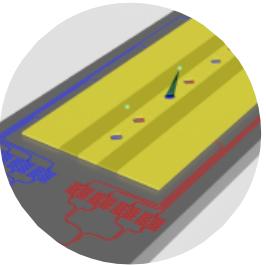
October 11<sup>th</sup>, 2024



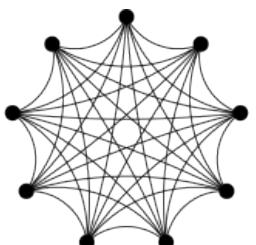
Sandia National Laboratories is a multimission laboratory managed and operated by National Technology & Engineering Solutions of Sandia, LLC, a wholly owned subsidiary of Honeywell International Inc., for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-NA0003525.



## Ion Trapping Overview



## Next Generation Ion Traps



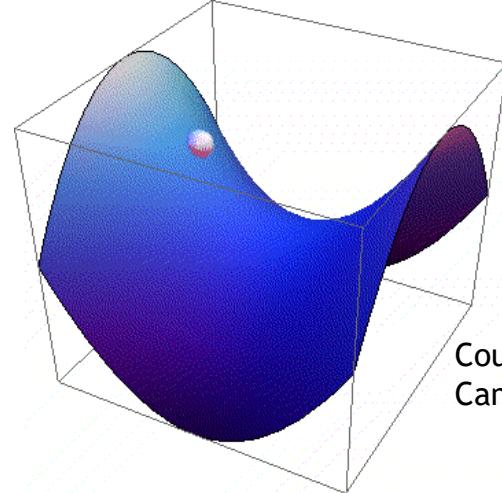
QSCOUT

# Earnshaw's Theorem and Ion Trapping



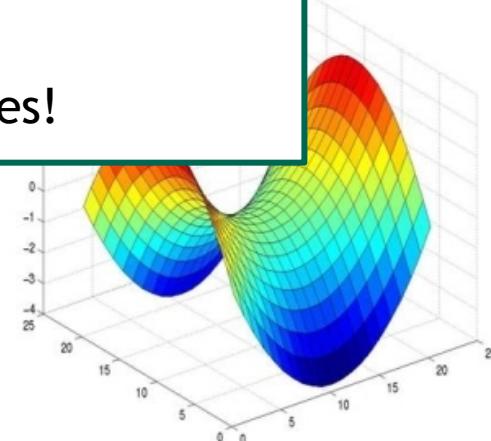
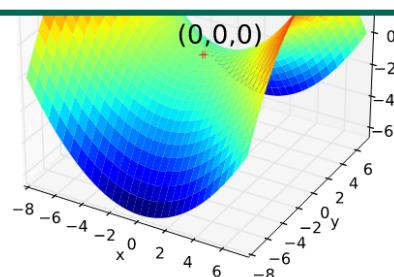
Trapping requirement: A restoring force when displaced from trap center  
(in any direction)

Cannot use  
t  
Field lines  
start/en



“out” and  
directions

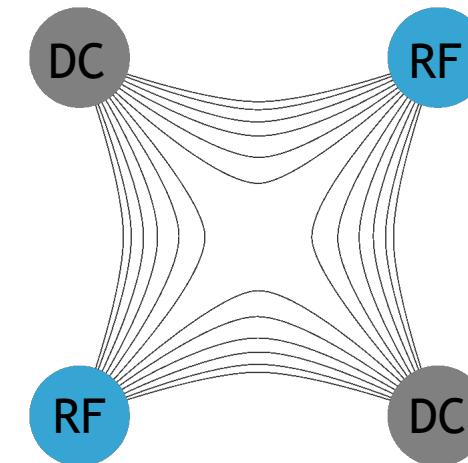
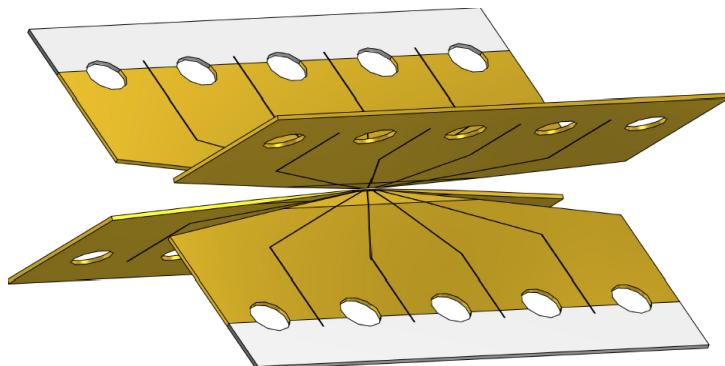
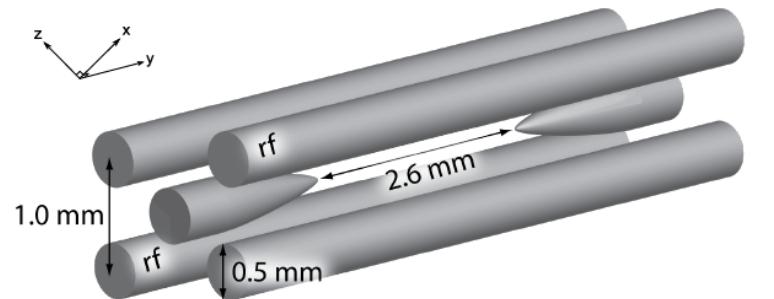
Before ion escapes, field reverses!



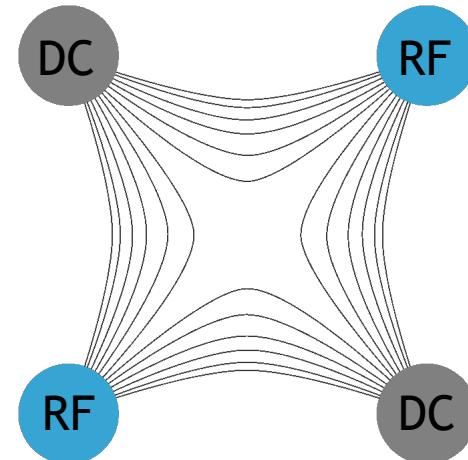
# Various Trap Geometries



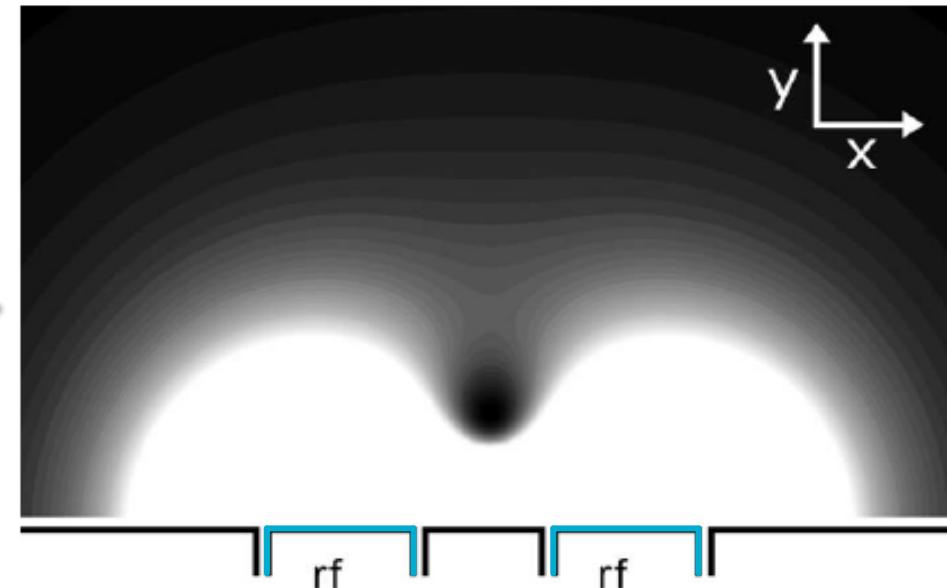
Use a combination of static and rf fields to trap ions  
Various geometries possible



# Various Trap Geometries

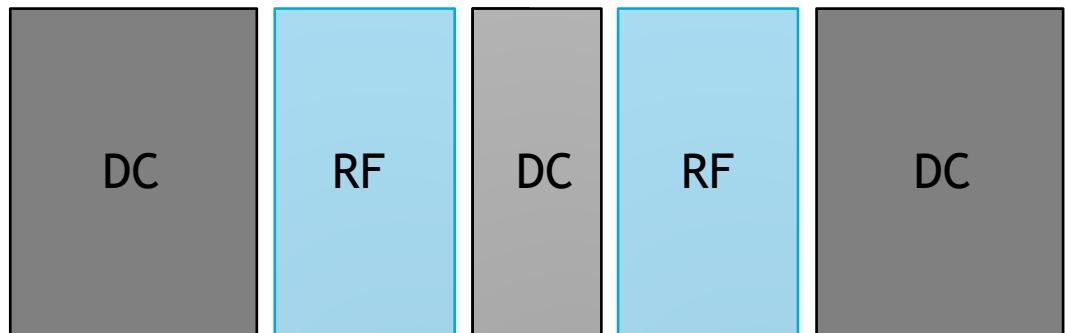


Pseudopotential well (dark area) formed along the axis of a surface trap

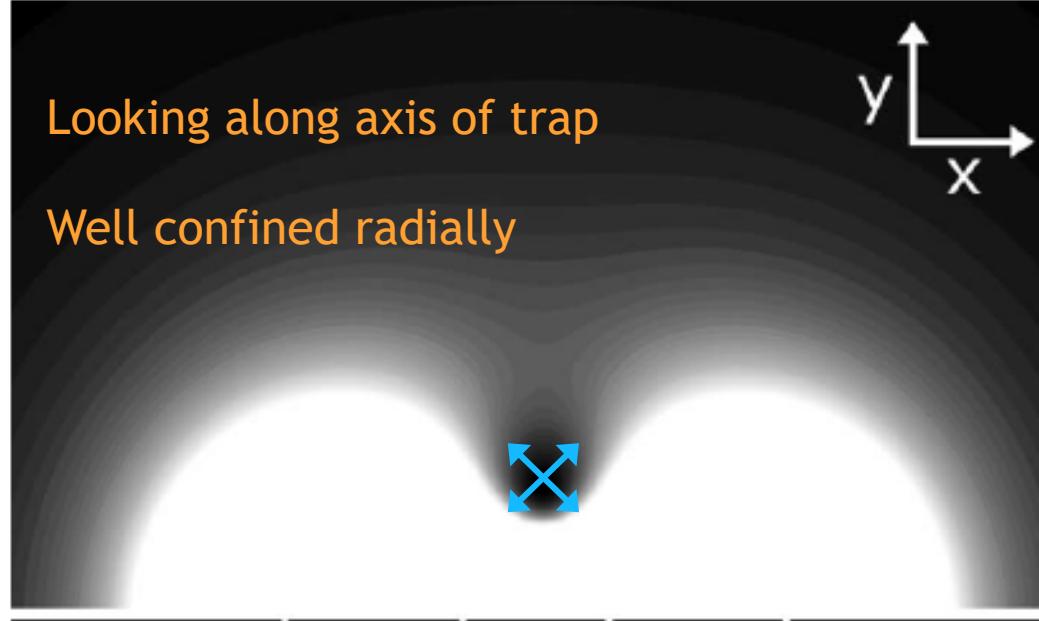


Electrodes from above

House, PRA 78 033402 (2008)

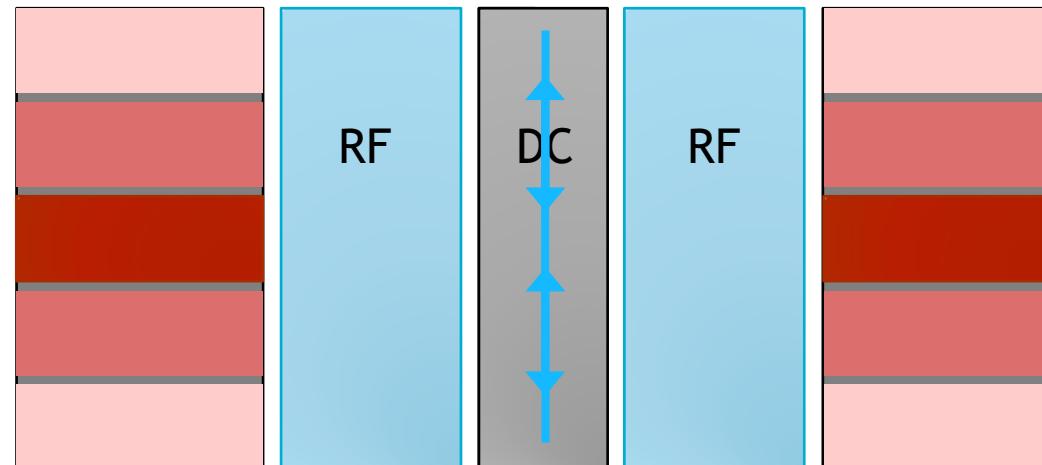


## 6 Need for DC Fields



Looking at trap from above

Still free to move along axis

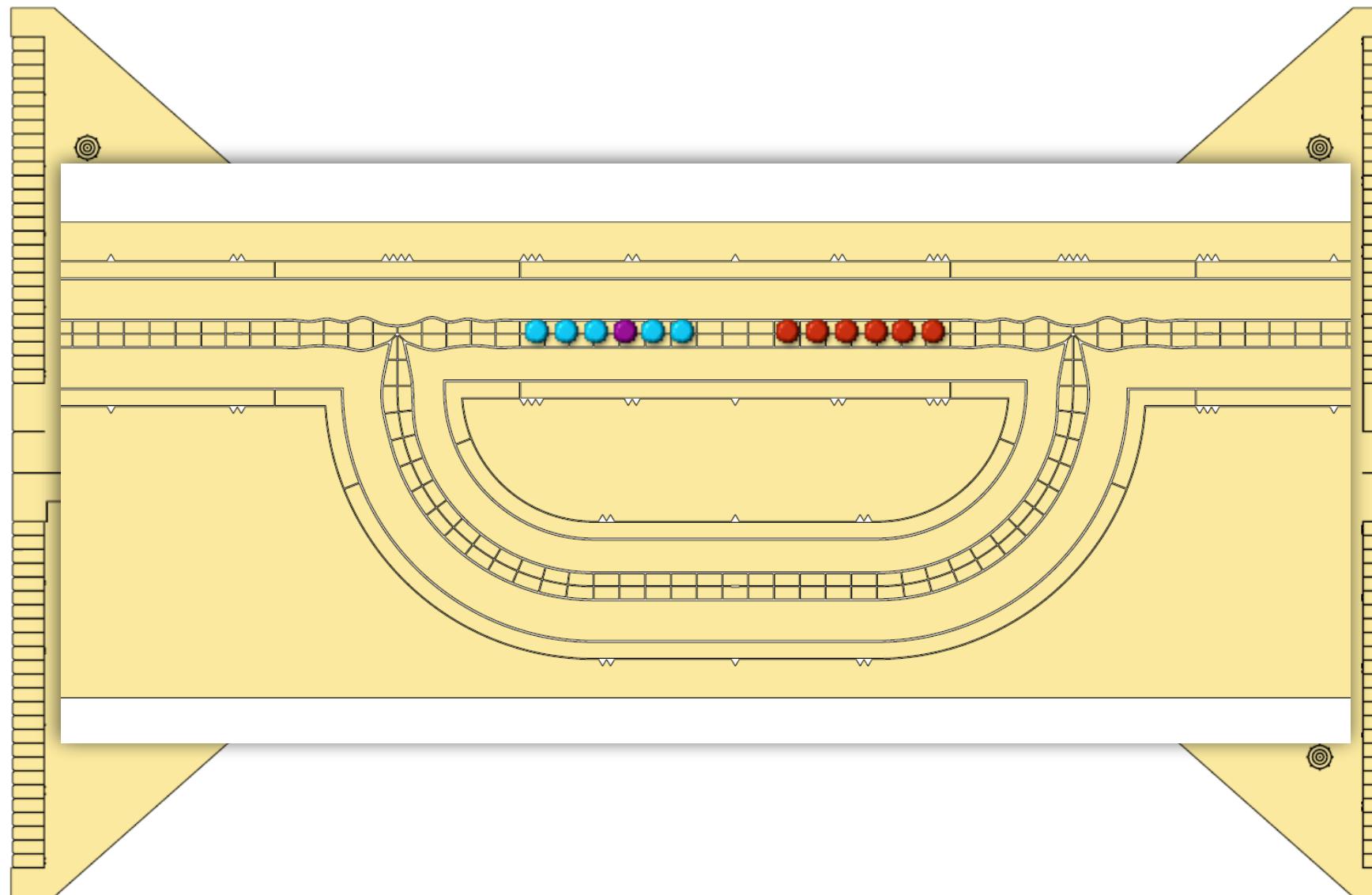


Use DC fields on the electrodes to confine

Creates a trapping potential along axis

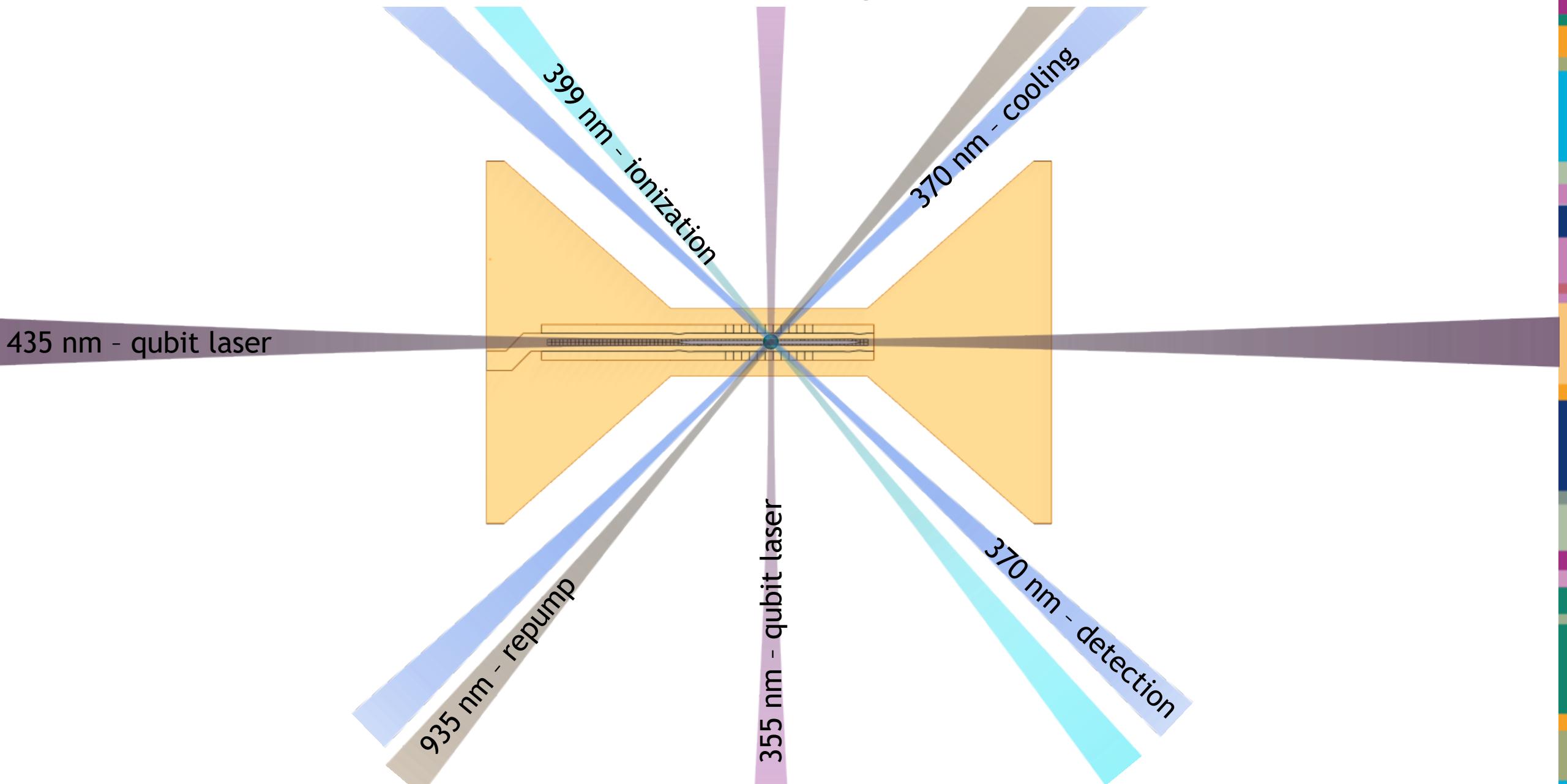


# Create custom trap designs with advanced ion control



QSCOUT - Jackrabbit trap

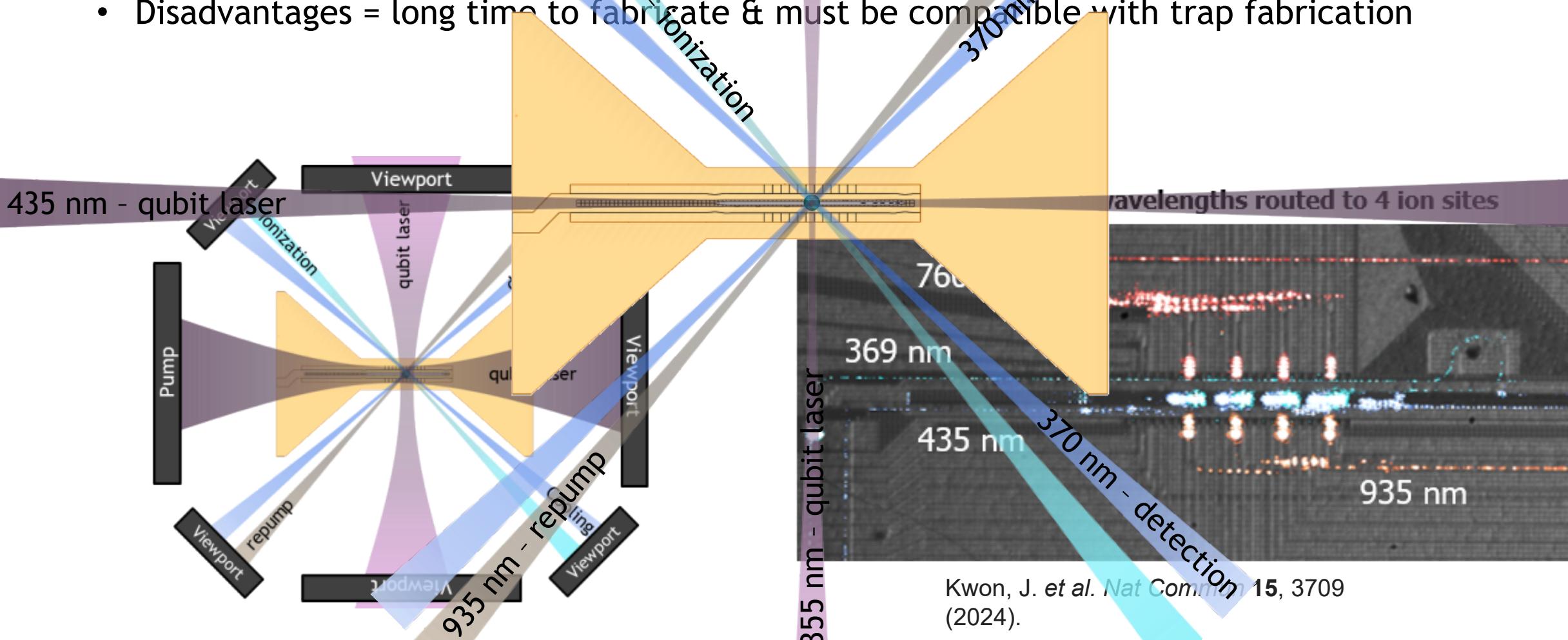
# Next Generation Traps – Increasing Optical Access



# What's Next? Integrated Photonics



- Integrated optics serve to **solve** the problem of scaling vacuum systems for trapped ion systems
- Direct integration = lithographic alignment
- Disadvantages = long time to fabricate & must be compatible with trap fabrication

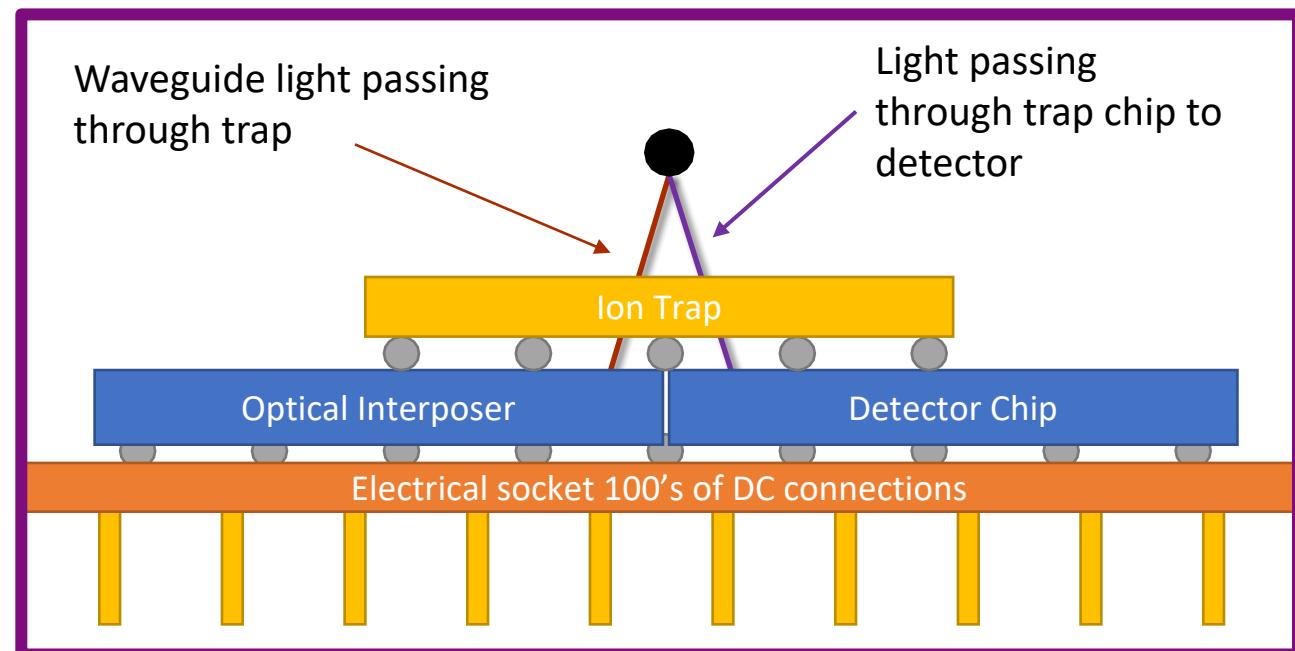
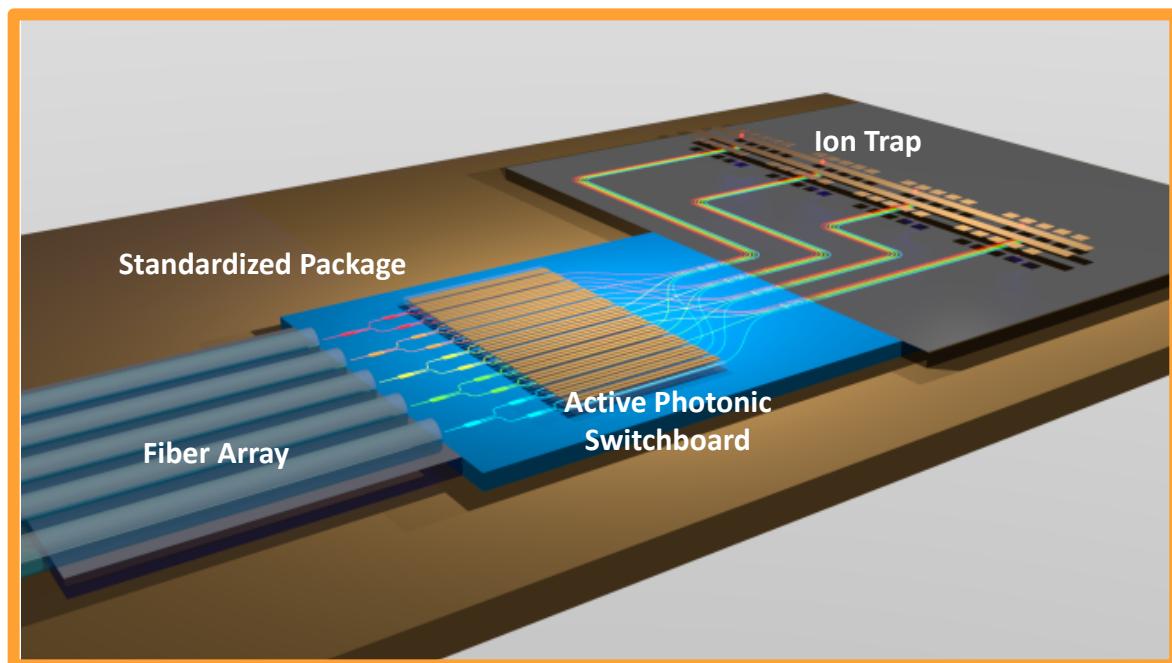


Kwon, J. et al. *Nat Commun* 15, 3709 (2024).

# Why Heterogenous Integration?



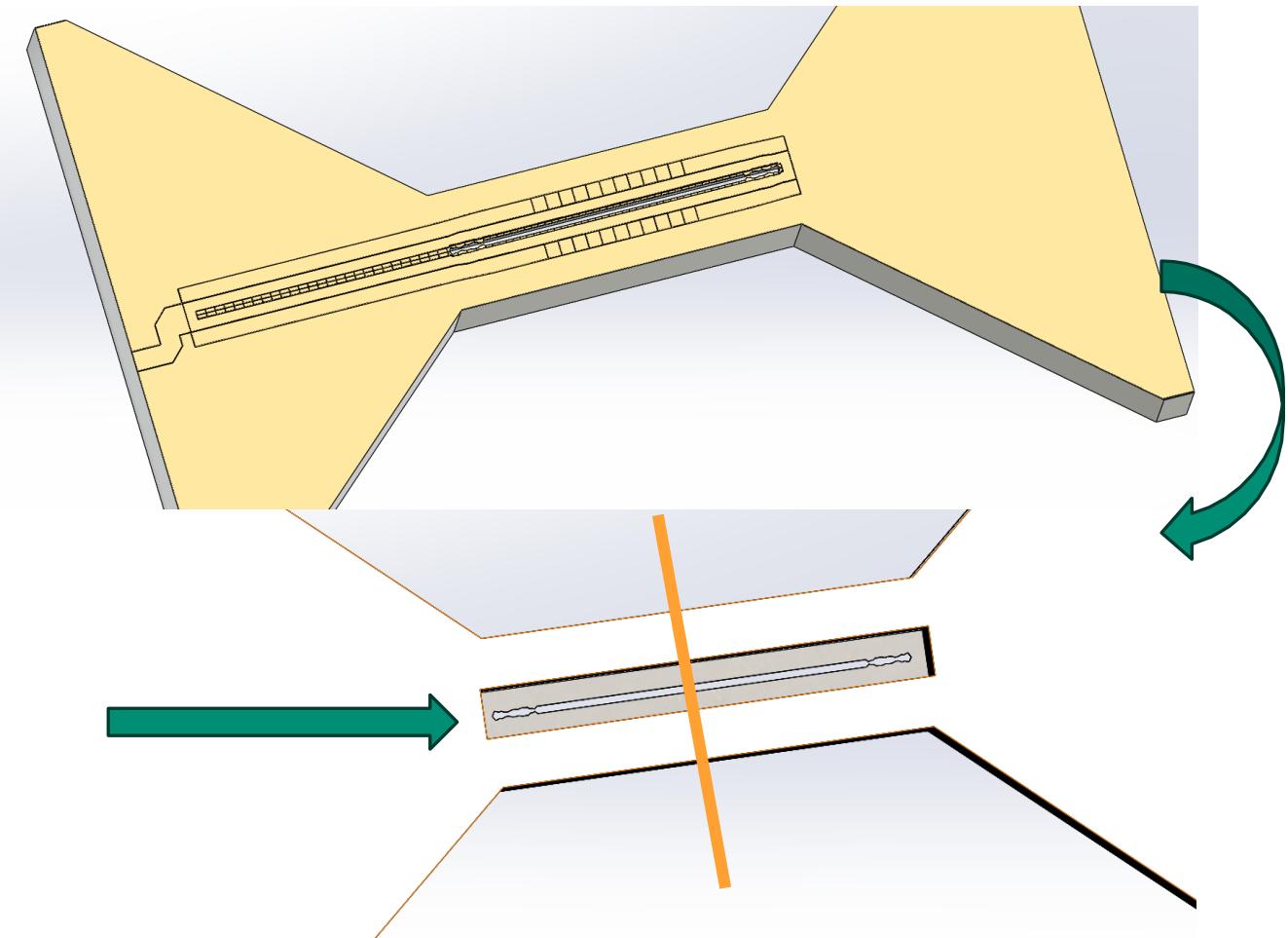
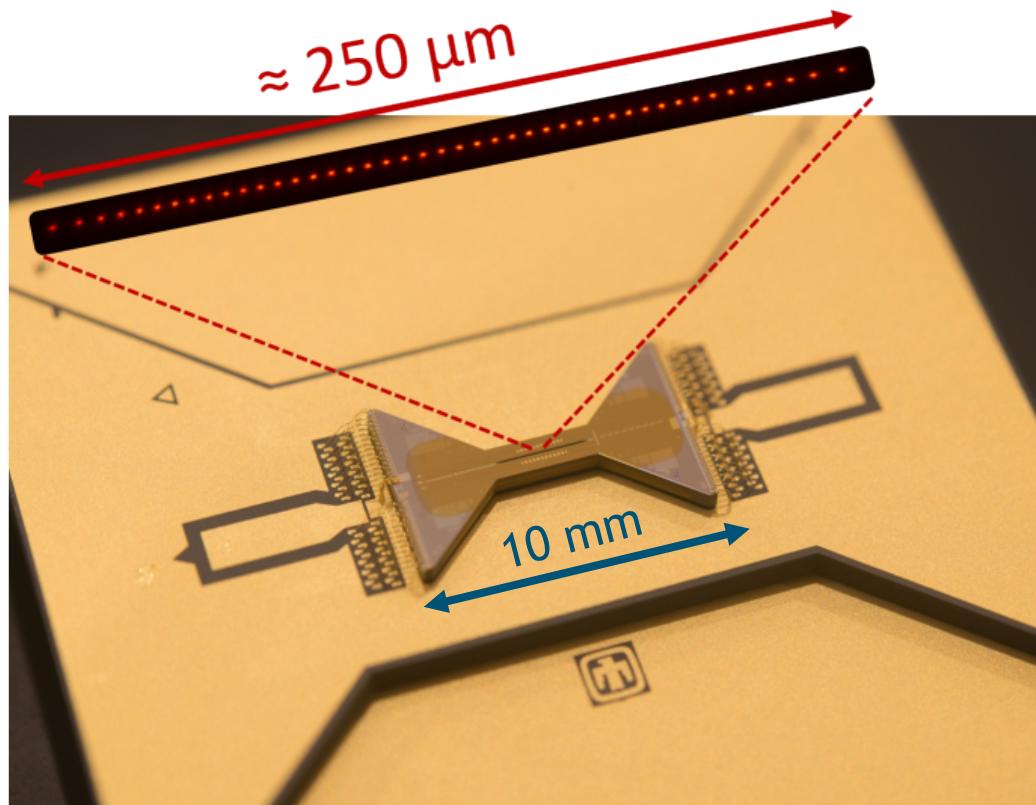
- By separating the pieces onto separate chips, we can enable faster development and more flexible designs
- Disadvantage: aligning separate pieces in a way that can survive a vacuum bake is hard
- Two different approaches:
  - A hybrid solution where exotic technology is off-chip = easier to integrate
  - The ion trap is completely separate from photonic (and other) technology



# Heterogeneous Integration: Waveguides + Phoenix Trap



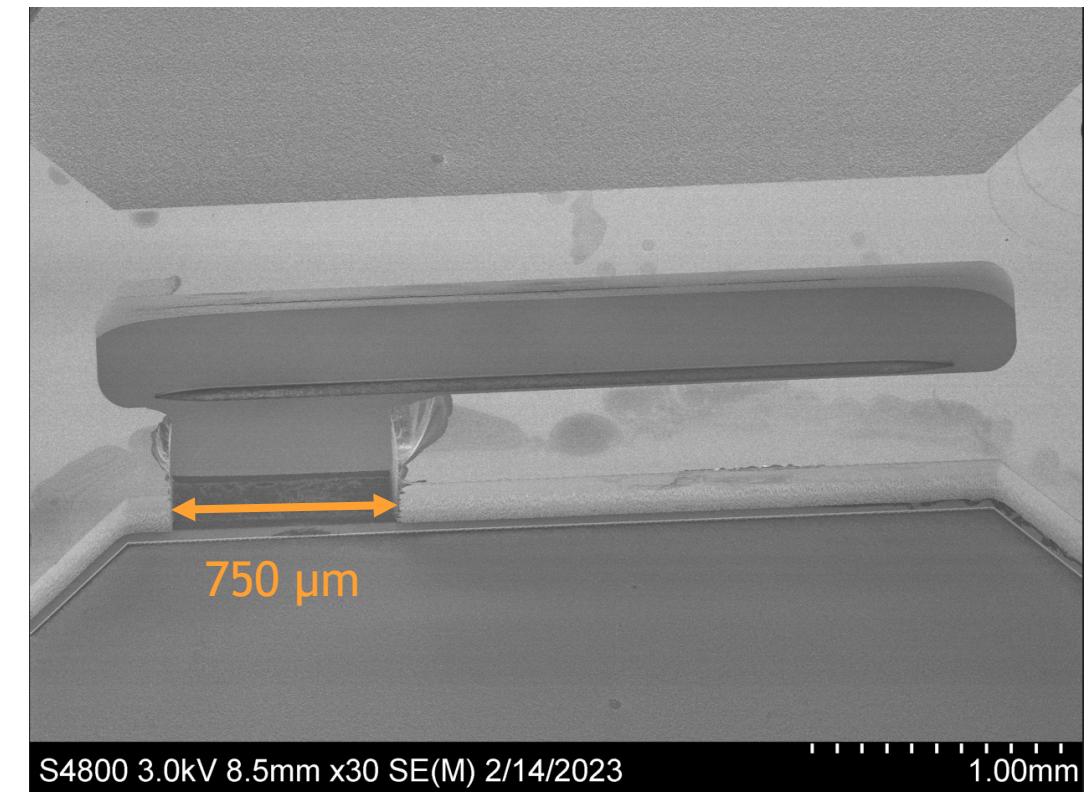
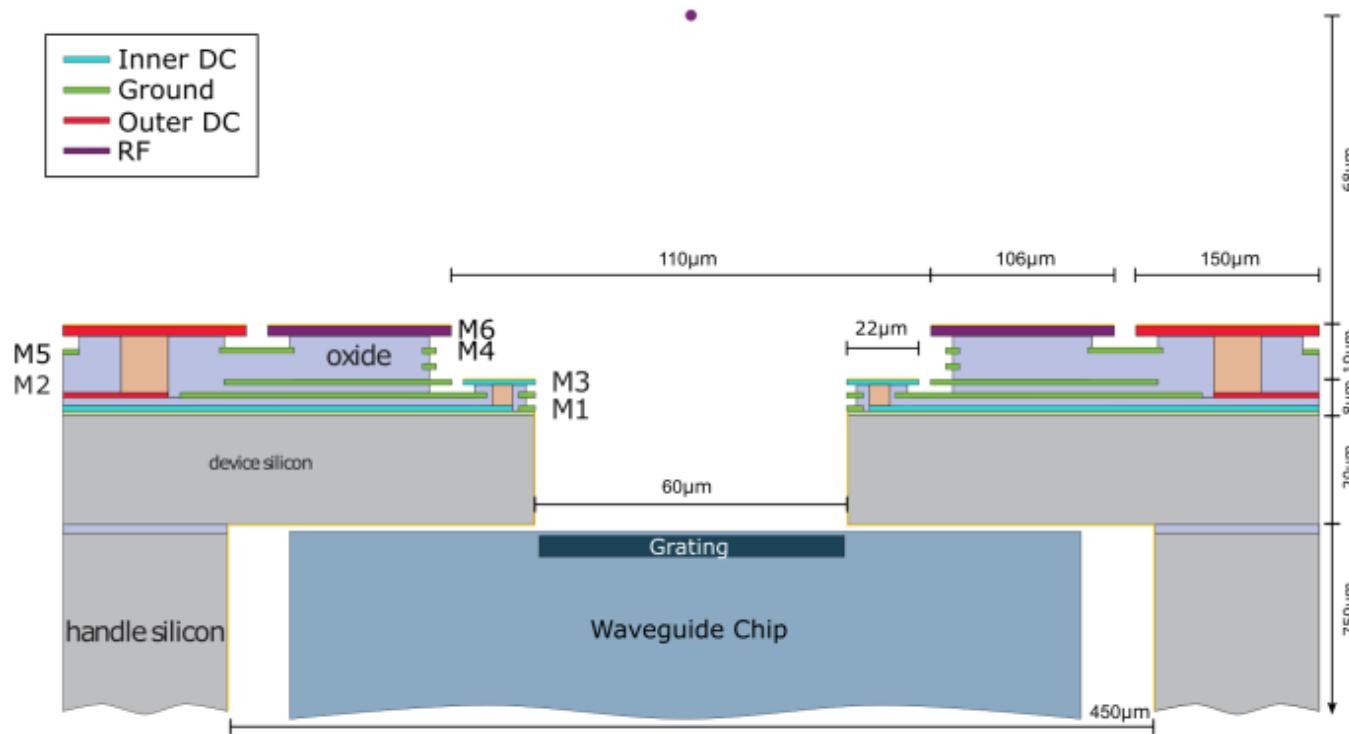
- Designed a 355nm waveguide chip to fit into a modified Phoenix trap
- “Micro-machining” a hole in the backside silicon to pass light through
  - Remaining handle silicon is 10um thick



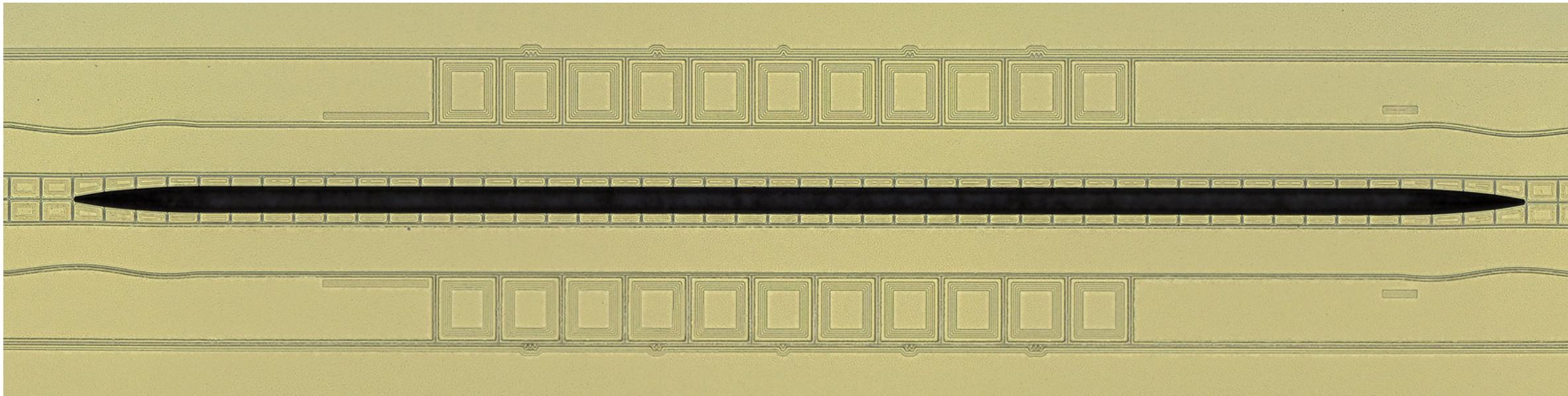
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- Designed a 355nm waveguide chip to fit into a modified Phoenix trap
- “Micro-machining” a hole in the backside silicon to pass light through
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# Characterize alignment using 355nm light and experiment

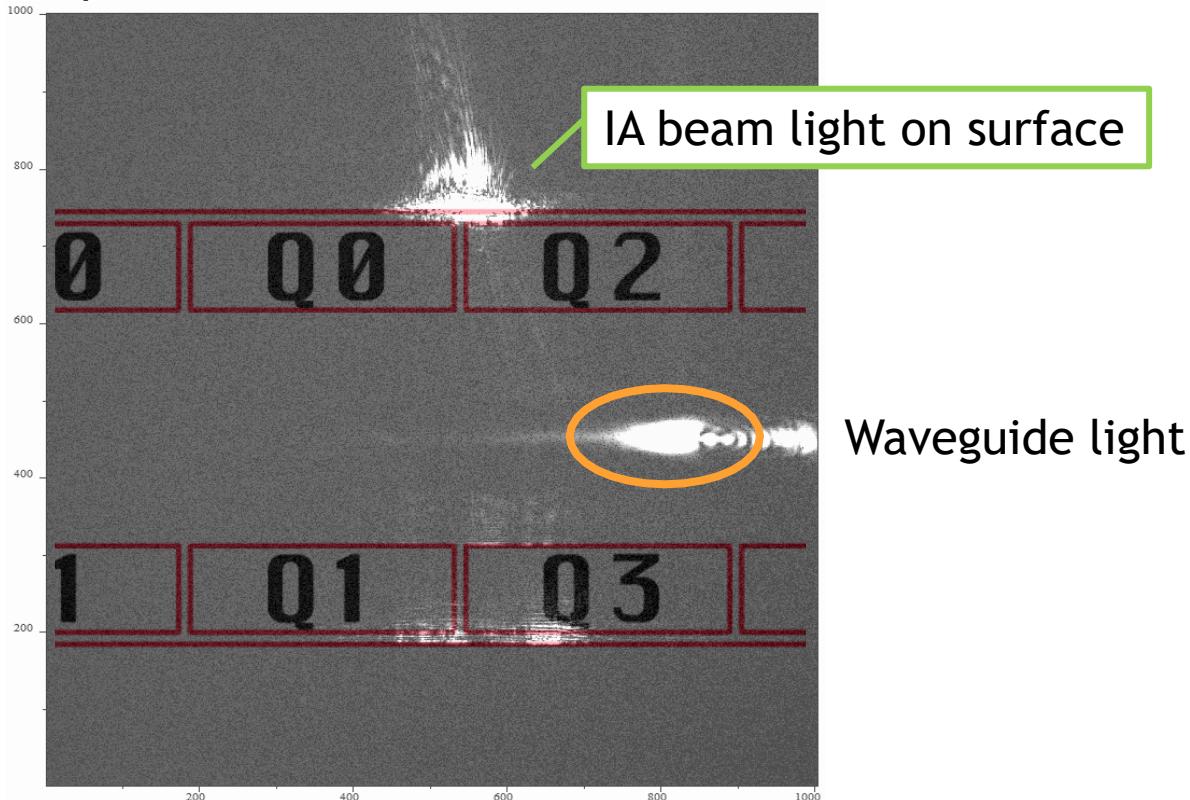
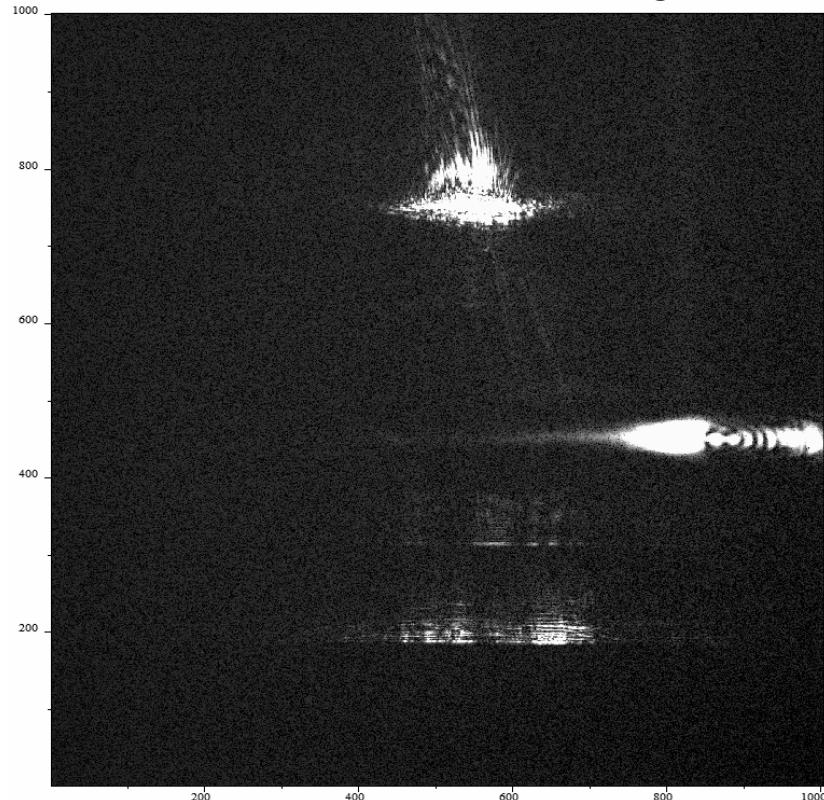


- Our trapped ion system has a high-zoom imaging system which allows for sub-micron precision in our measurements.
- We can track the light out of the waveguide with respect to the surface to determine how the waveguide shifts during a vacuum bake
  - Use the same wavelength across the surface to find the electrode edges
  - Track the light out of the waveguide as we change the focus of the imaging system getting snapshots as a function of height from the waveguide chip

# Characterize alignment using 355nm light and experiment



355 light in focus at trap surface

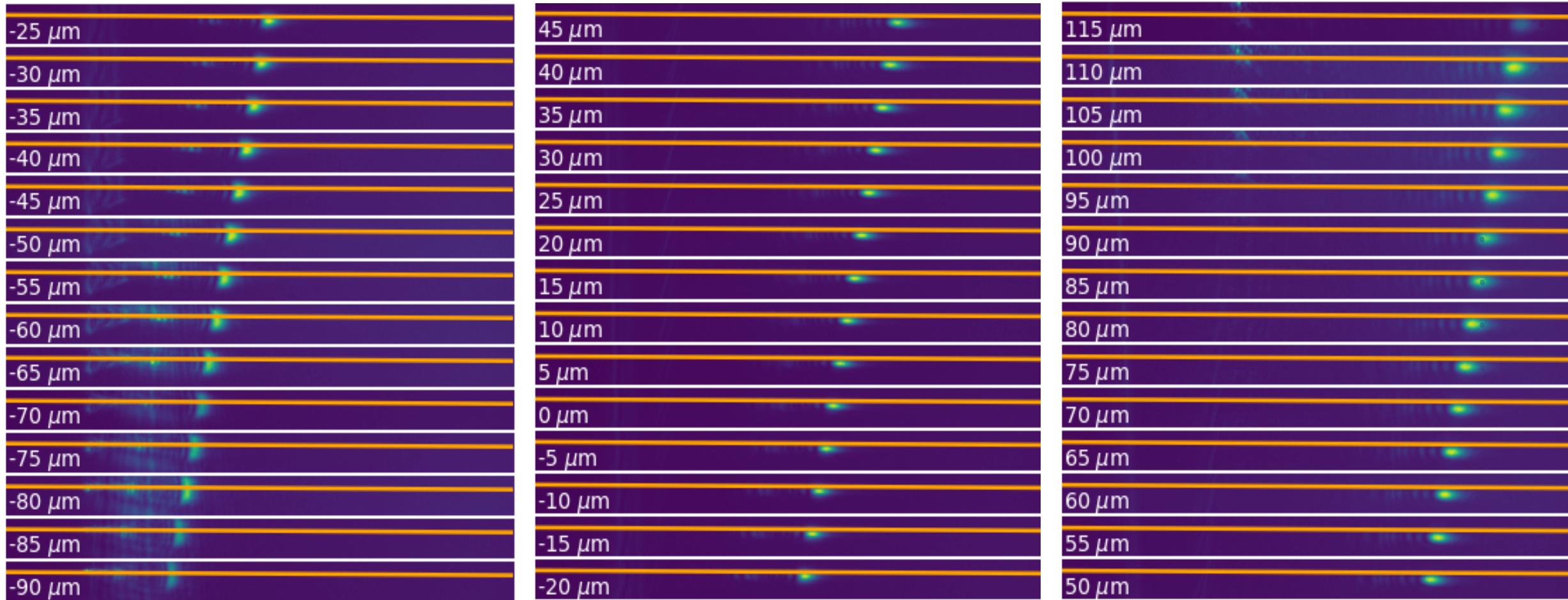


- By calibrating the imaging, we can track the output of the waveguide with respect to the ion trap chip
- Our magnification give us  $\sim 0.28\mu\text{m}/\text{pixel}$  on the camera with  $\sim 1\text{pixel}$  uncertainty as long as the lens motors move in a single direction

# Before baking track the output vs height from ion trap chip



- Using the location of the edges of the trap, we compare the output of the waveguide to the center of the trap



# Compare output before and after bake

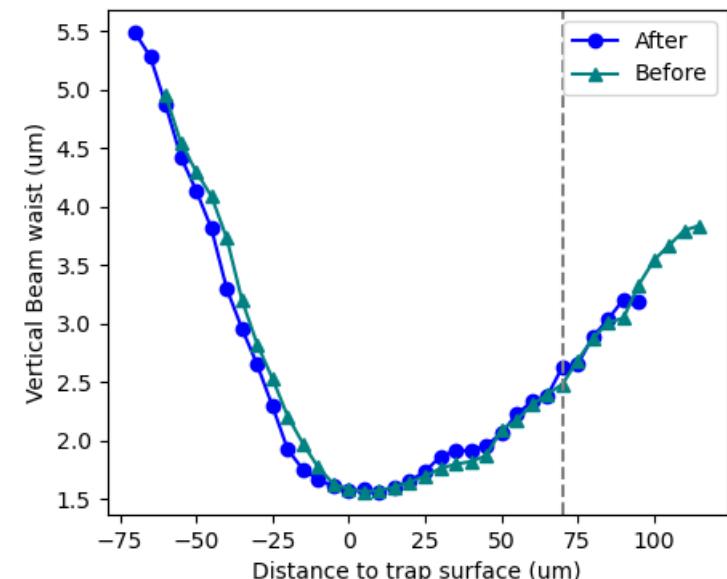
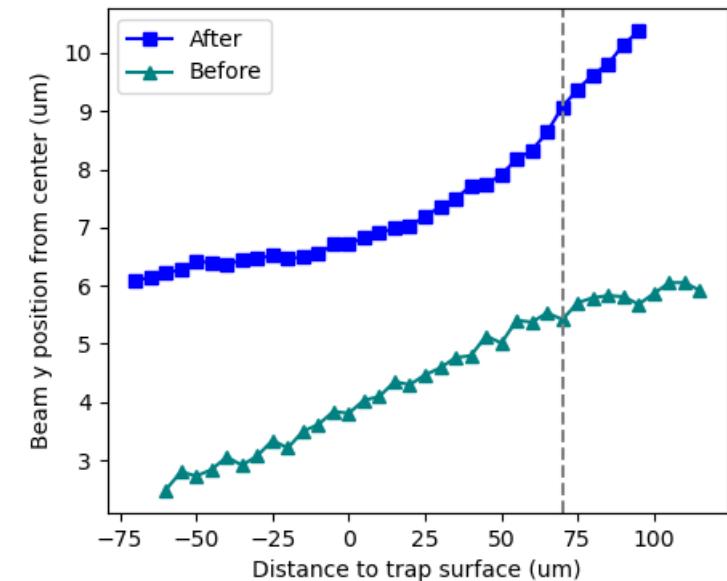


- Though AuSn solder should be resistant to shifting during a 150C bake, we see that the chip does shift after 5 days of baking
- We measure about 3 um of shift from a 5 day bake
- Need to develop a technique that reduces stress in the solder attach to minimize the motion

Before bake



After bake



# Solder Will Move to Relax Stress



- A study has shown a relationship between temperature and stress a solder creep rate [1].

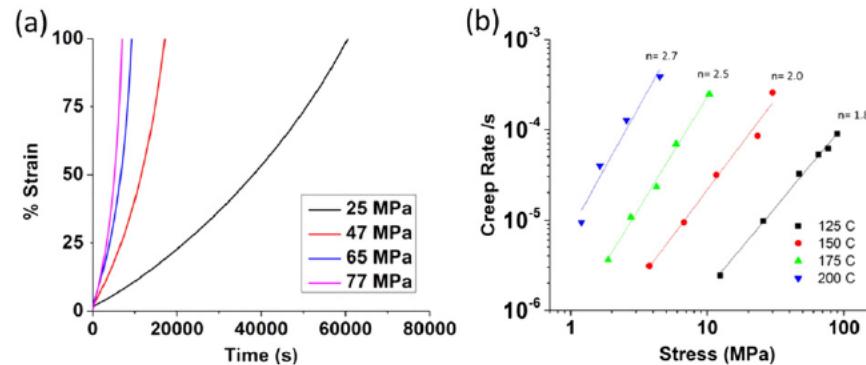
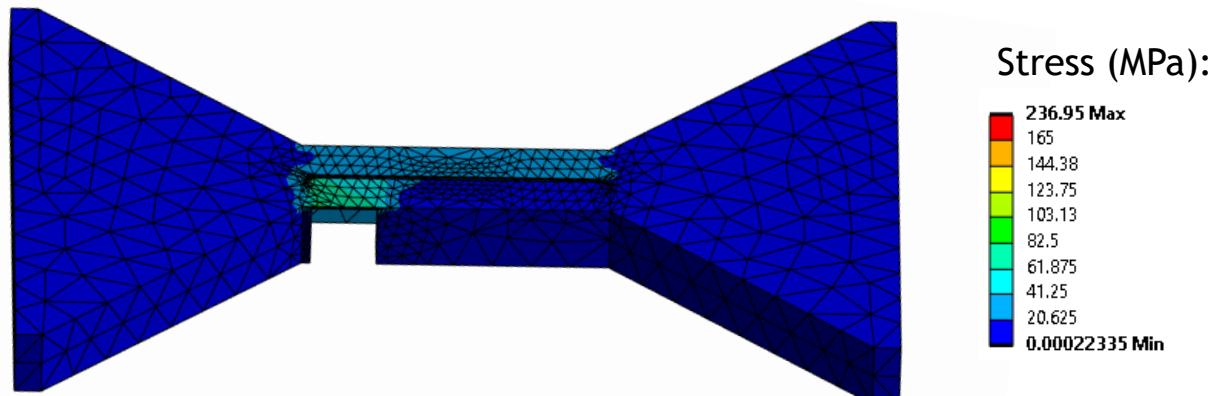


Fig. 3. a) Creep curves of AuSn at 125 °C, truncated at 100% strain, and b) creep rates of AuSn between 125 and 200 °C. The power law stress exponent,  $n$ , is indicated for each temperature.

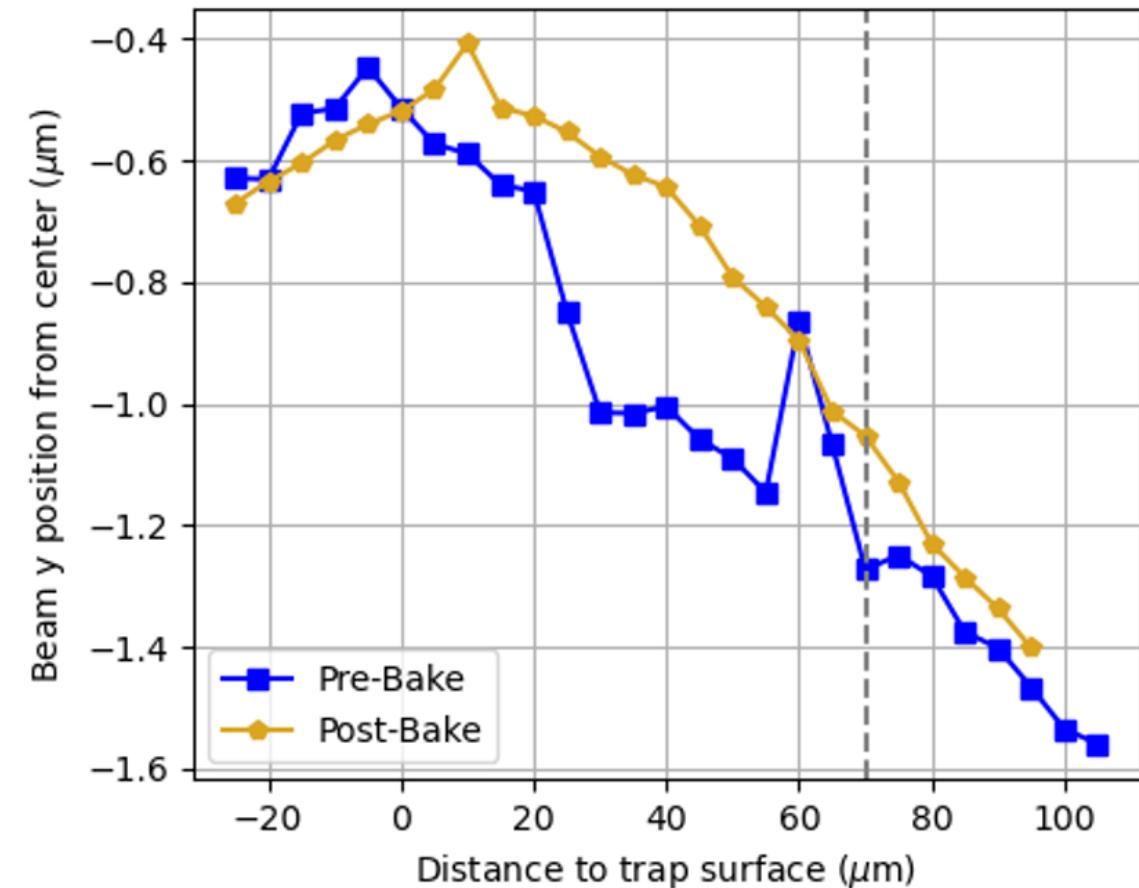
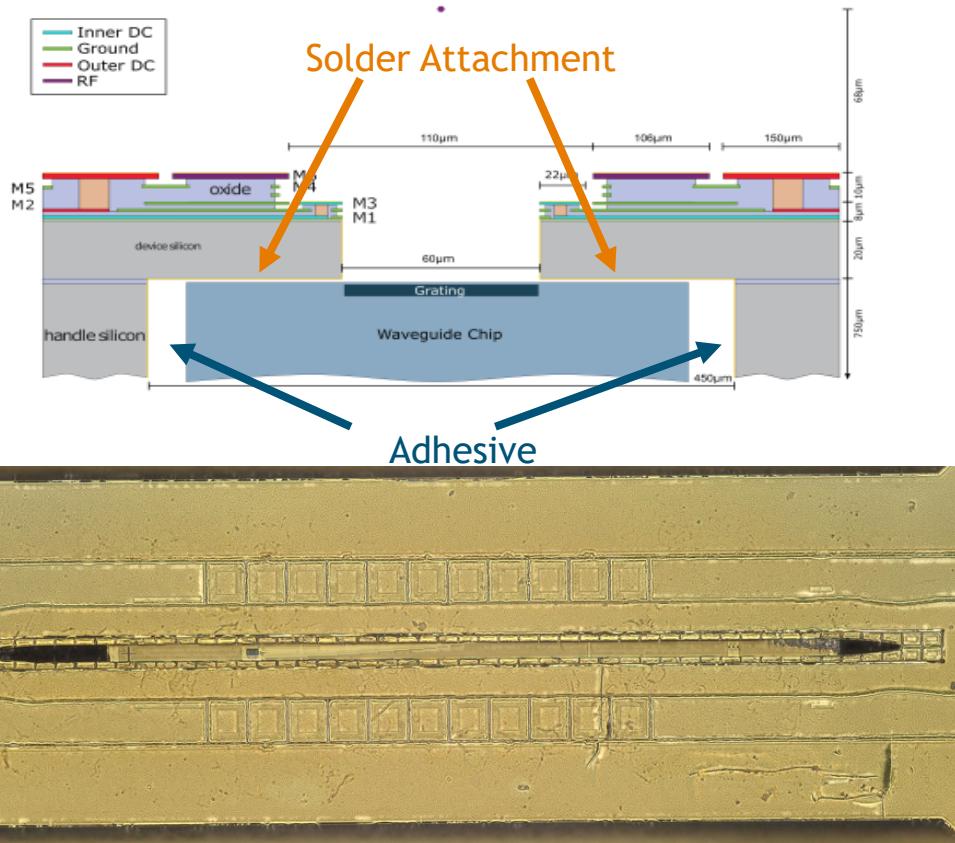
- For AuSn that melts at 280 °C, the temperature range of 125 to 200 °C represents a homologous temperature,  $T / TM$ , range of 0.72 to 0.86
- We know that 150 °C falls exactly here which is demonstrated in this paper to incur creep.
- The region where the waveguide is mounted is suspected to have the highest stress, suggesting this cause



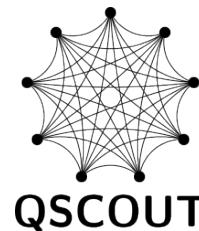
# Reinforcing the Solder with Adhesive



- We can use an established HI practice and underfill the soldered piece with an adhesive
- Trap surface is too damaged for trapping
- Reduced the amount of shift to  $< 0.5 \mu\text{m}$



# Quantum Scientific Computing Open User Testbed (QSCOUT)



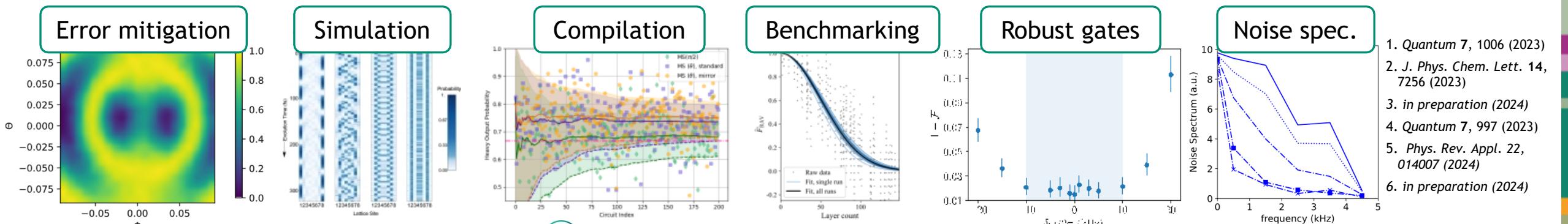
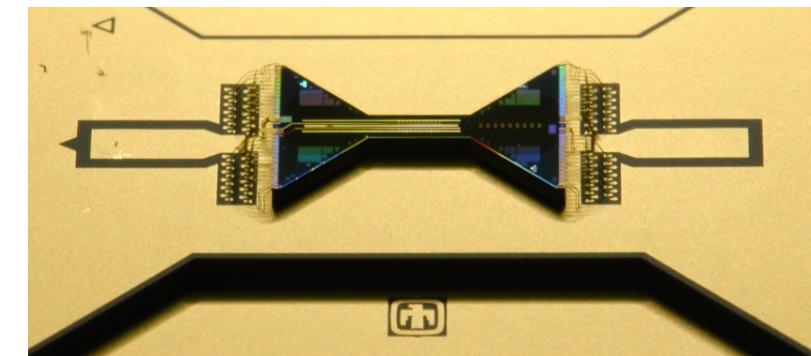
[qscout.sandia.gov](http://qscout.sandia.gov)  
qscout@sandia.gov



A quantum computing testbed based on trapped ions for the greater quantum scientific community  
QSCOUT grants low-level access to quantum machines for free to researchers around the world to study their proposed research.

## QSCOUT goals:

- Greater understanding of how quantum machine work (and fail)
- Study new techniques for encoding and compiling quantum circuits
- Construct a roadmap for building larger, more sophisticated machines



# Current Specifications of the Machine

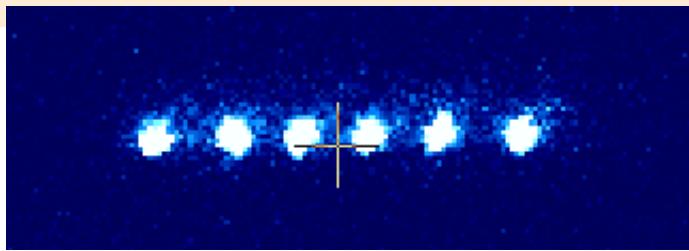


## Current Specs:

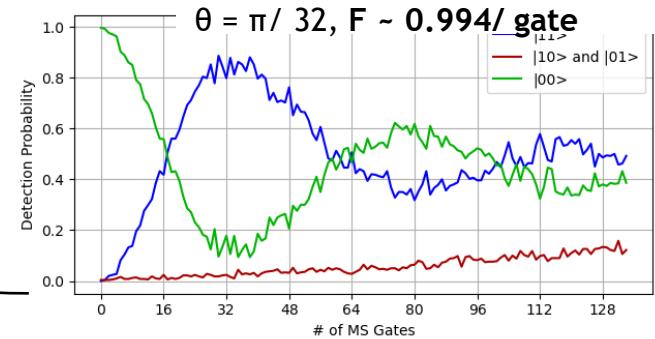
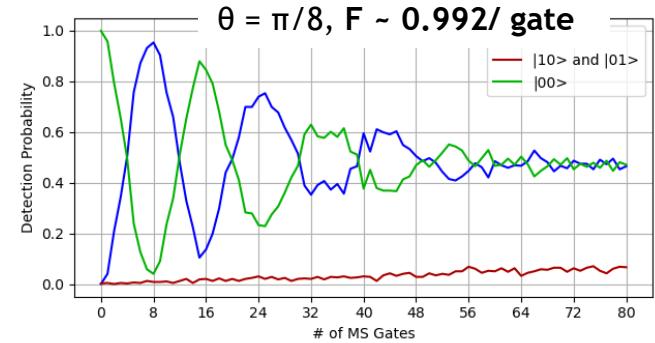
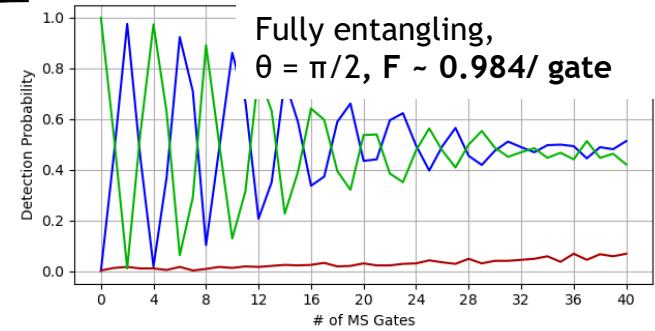
- 6 ions, fully connected, individually addressable
- >0.96 fidelity two-qubit gate (any pair)
- >0.997 fidelity single-qubit gate
- >0.998 fidelity state preparation and measurement
- Can provide custom calibrations
- Can specify phase and amount of entanglement for 2-qubit Mølmer-Sørensen<sup>1</sup> ( $\sigma_i \times \sigma_i$ ) gate (use as little entanglement as needed)

<sup>1</sup>Mølmer and Sørensen, *PRL* **82**, 1835 (1999)

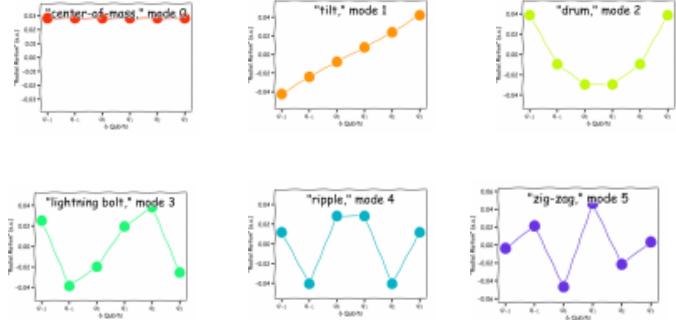
Clark *et al.* *IEEE TQE* **2**, 3102832 (2021)



## Repeated MS gates of different entangling angles



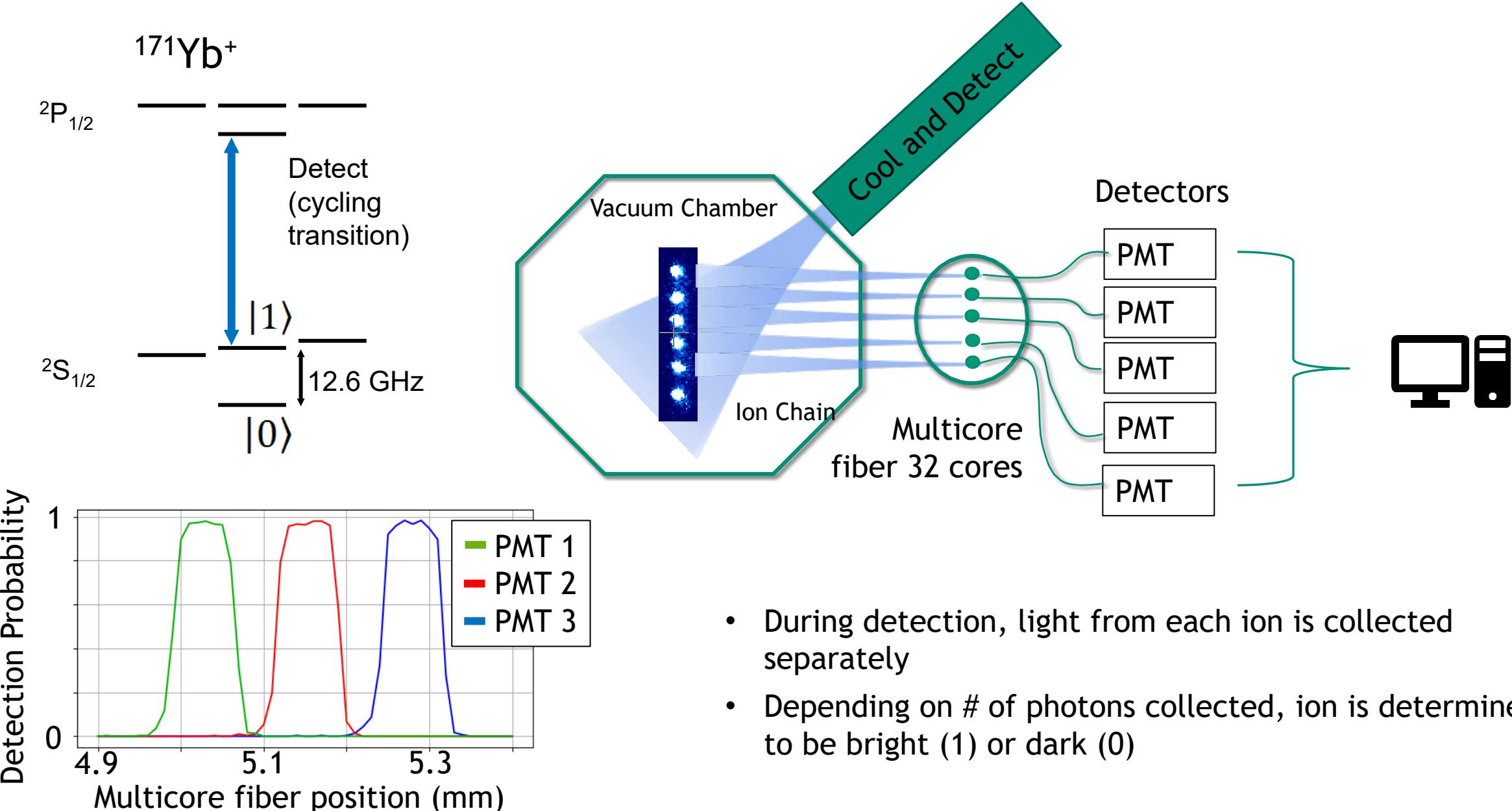
## Motional modes of 6-ion chain



## 6-ion chain MS gate pairs fully entangled estimated state fidelities

Pair index	q[a]	q[b]	Mode index	Detuning (kHz)	Fidelity (%) [+1%, -2%]
0	0	1	5	43	97.1
1	2	0	4	30	95.6
2	2	1	5	35	96.8
3	0	3	5	36	95.4
4	1	3	4	35	97.8
5	2	3	4	30	93.5
6	0	4	2	22	95.9
7	1	4	3	20	95.7
8	2	4	3	26	95.9
9	3	4	3	26	95.4
10	0	5	3	23	94.0
11	1	5	2	22	94.7
12	2	5	3	25	94.7
13	3	5	2	20	93.6
14	4	5	2	20	95.2

# Light from each ion is directed to its own detector



# Copropagating or counterpropagating configurations as needed

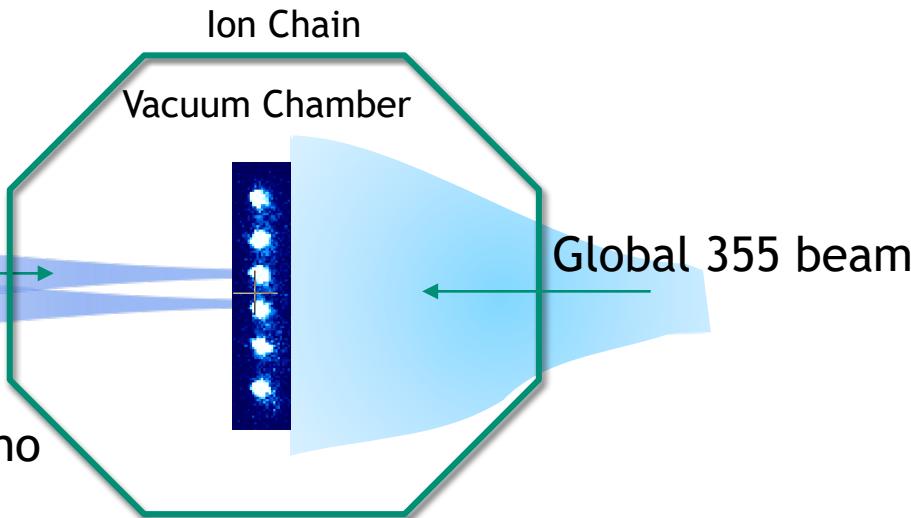


23

32 channel AOM, each channel controllable in frequency phase and amplitude

Individual 355 nm beams

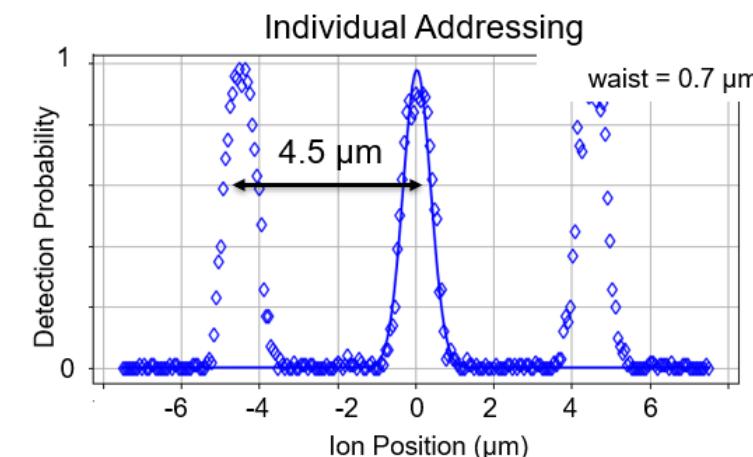
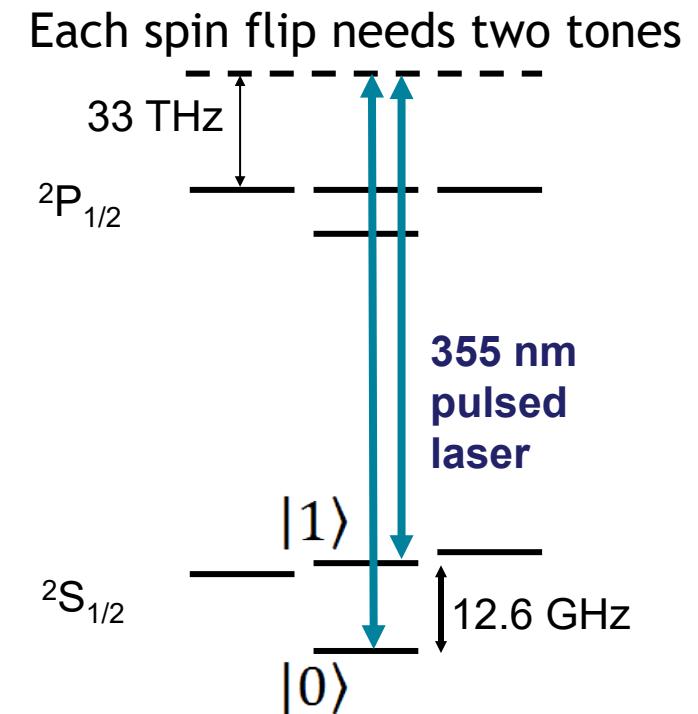
Single qubit gates, use two tones on each individual beam (no global beam)



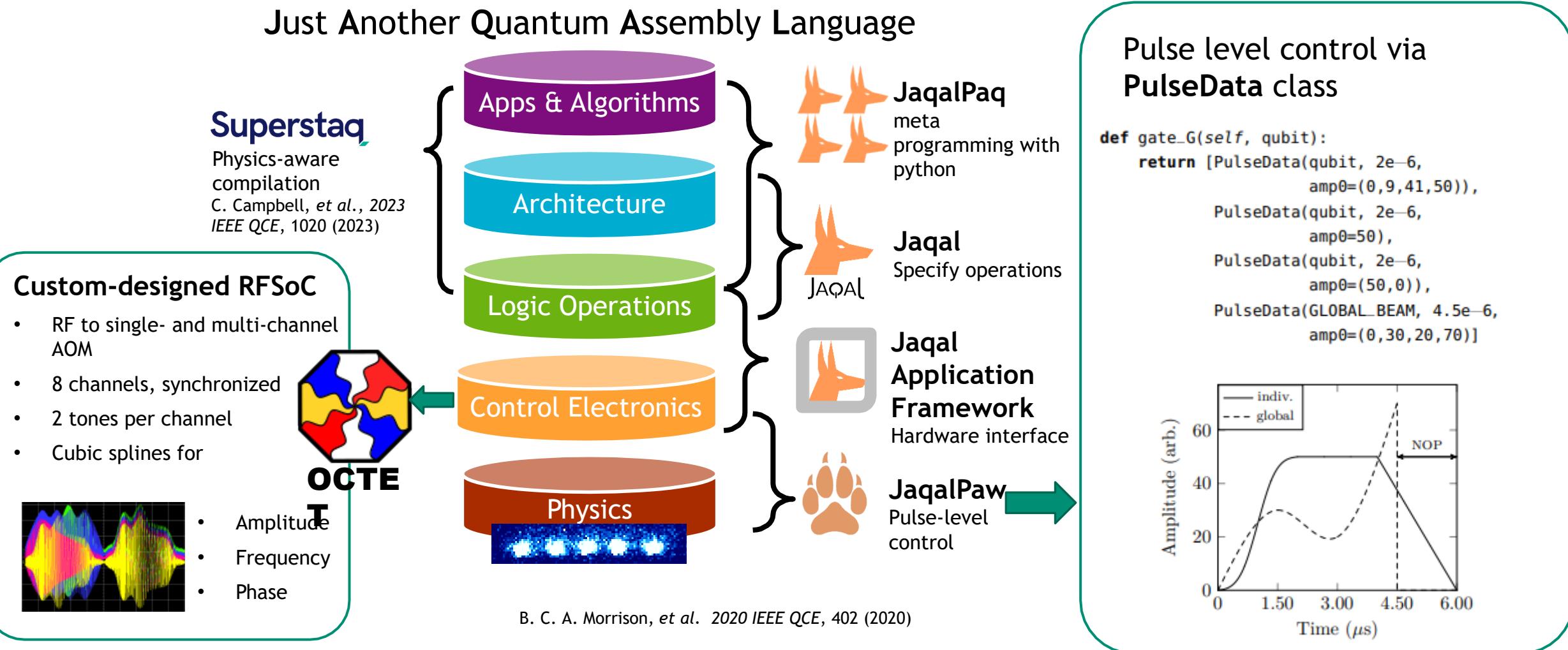
## Two Qubit Gates with Trapped Ions:

- Mølmer-Sørensen<sup>1</sup>  $\sigma_i \times \sigma_i$  entangling interaction (choose your basis)
- Three frequencies required, counterpropagating configuration required (2 freq on individual channel, 1 freq on global channel)
- Any pair of ions can be illuminated, excite and de-excite motion of whole chain, only illuminated ions experience spin flip needed for entanglement

<sup>1</sup>Mølmer and Sørensen, *PRL* 82, 1835 (1999)



# QSCOUT uses Jaqal programming language



# Scientific progress through low-level access: Infleqtion



Low-level native-gate aware compilation techniques to improve circuit performance

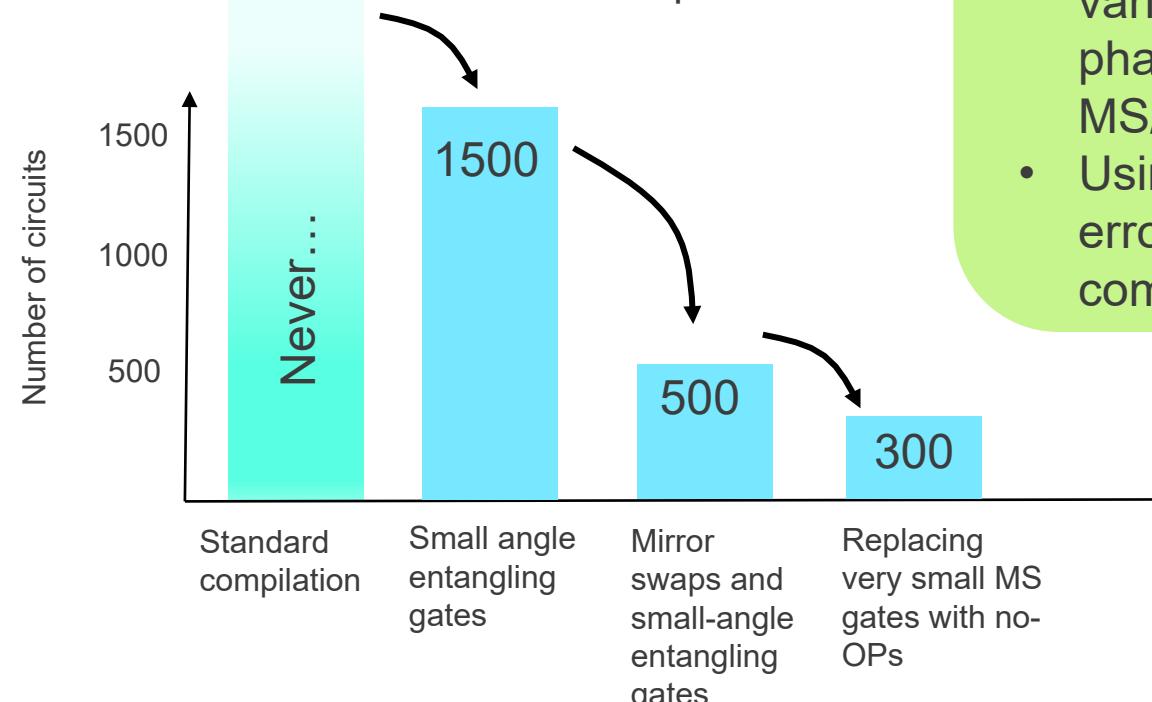


Benjamin Hall, Victory Omole, Rich Rines, Pranav Gokhale (PI)

Other user teams have incorporated Superstaq optimizations

User team	Optimization type	Benefit provided
LCN LONDON CENTRE FOR NANOTECHNOLOGY	ZZ( $\theta$ ) instead of MS( $\pi/2, \emptyset$ )	Higher fidelity circuits, Shorter circuits
OAK RIDGE National Laboratory	Fewer single qubit gates	Shorter circuits Simpler circuits
UCDAVIS	ZZ( $\theta$ ) and mirror swaps	Higher fidelity circuits Shorter circuits
ETH zürich		

Given our error rates, compared how many circuits are required to show a convincing Quantum Volume =  $2^4$  measurement for different methods of compilation



## Why QSCOUT?

- Fully parametrized 2-qubit gates
- Pulse-level access to define new gate variants (ZZ and phase agnostic MS/ZZ gates)
- Using physical gate errors to inform compilation choices

# Scientific progress through low-level access: Oak Ridge

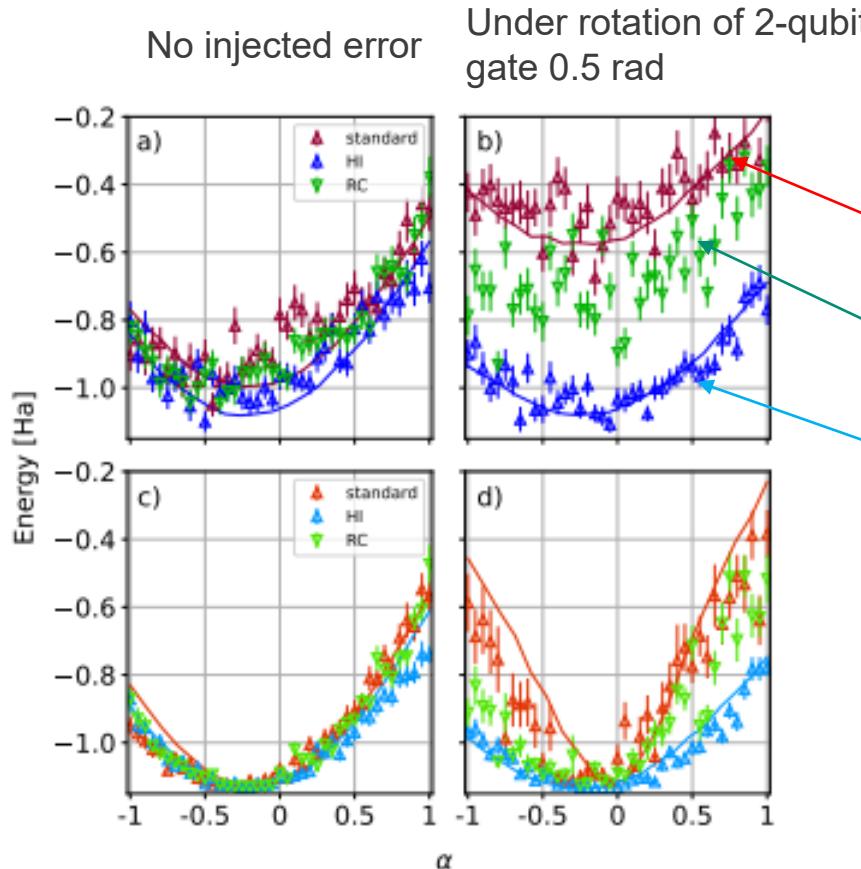


Characterizing and Mitigating Coherent Errors in a Trapped Ion Quantum Processor Using Hidden Inverses



Quantum 7, 1006 (2023)

S. Majumder, T. D. Morris, Raphael Pooser (PI)



Variational Quantum Eigensolver Algorithm with swept parameter

No error mitigation

Randomized Compiling

Hidden Inverse

- Connecting low-level characterization techniques to higher level algorithmic performance
- Use error mitigation to determine types of errors in the system

Why QSCOUT?

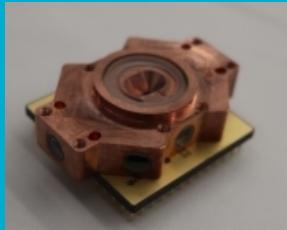
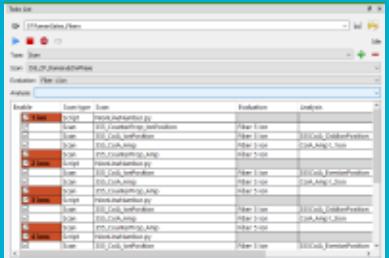
- Purposefully injected noise (different types)
- Able to run sequences back to back

# Moving forward, 3 main goals for QSCOUT:



1. Improving uptime of the machine and increasing user base
2. Improving performance of the machine
3. New features and access

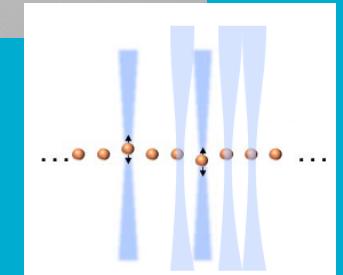
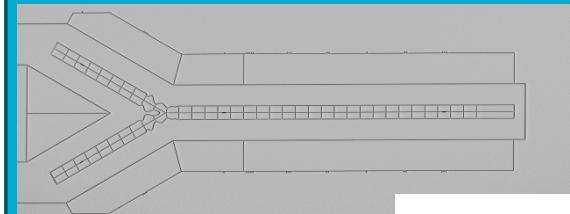
- Automated calibration
- Increased number of systems
- More representative noise models



- More ions
- Higher fidelity operations
- Lower heating rates/improved cooling
- Fast feedback for drift control



- Mid-circuit measurements
- Multi-ion entangling gates
- Fast feedback
- User request





# THANKS TO THE CURRENT TEAM

## *Experiments*

Ashlyn Burch  
Matthew Chow  
Susan Clark  
Josh Goldberg  
Craig Hogle  
Jeff Hunker  
Megan Ivory  
Loic Ijzerman  
Joon Kwon  
Ryan Law  
Daniel Lobser  
Brian McFarland  
Hayden McGuinness  
Theala Redhouse  
Melissa Revelle  
Jon Sterk  
Dan Stick  
Christopher Yale

## *Trap design, fab, packaging* *Integrated optics*

Matt Delaney  
Ray Haltli  
Ed Heller  
Tipp Jennings  
Nick Jimenez  
Zach Meinelt  
Chris Nordquist  
Eric Ou  
Ben Thurston  
Jay Van Der Wall

Daniel Dominguez  
Matt Eichenfield  
Mike Gehl  
Nick Karl  
Galen Hoffman  
Rex Kay  
Andrew Leenheer



Sandia  
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**ENERGY**

Office of Science



**LPS**  
The Laboratory for Physical Sciences

<https://www.sandia.gov/quantum/>